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Applicability of digital silicon photomultipliers in RICH detectors

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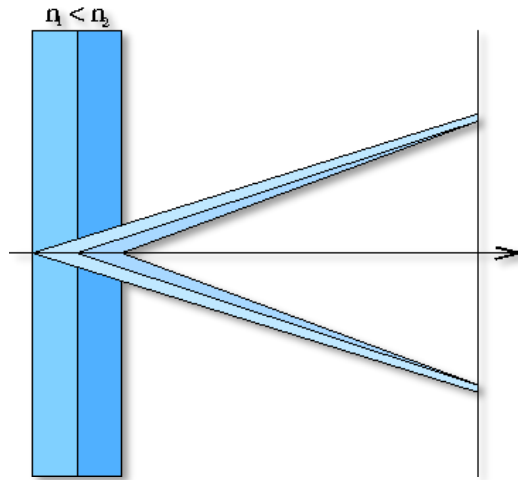
^c *Novosibirsk State Technical University*

International Conference on the Advancement of Silicon Photomultipliers

11-15 June 2018

Schwetzingen, Germany

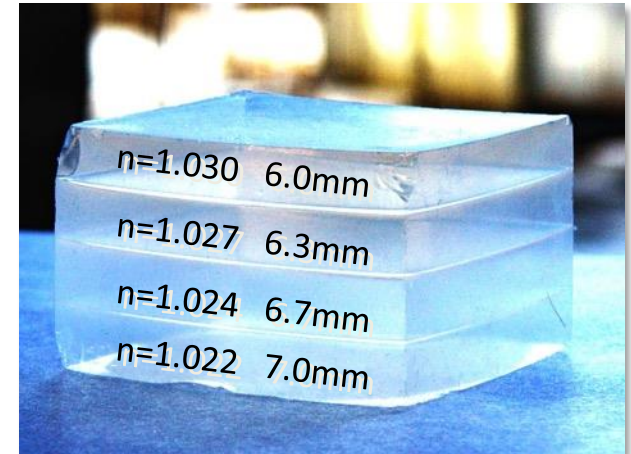
Focusing Aerogel RICH (FARICH)



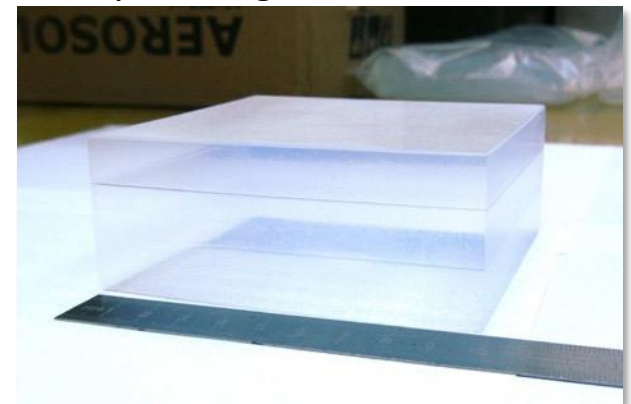
Focusing aerogel improves proximity focusing design by reducing the contribution of radiator thickness into the Cherenkov angle resolution

Multi-layer monolith aerogels have been being produced by the Boreskov Institute of Catalysis in cooperation with the Budker INP since 2004.

First sample of 4-layer aerogel

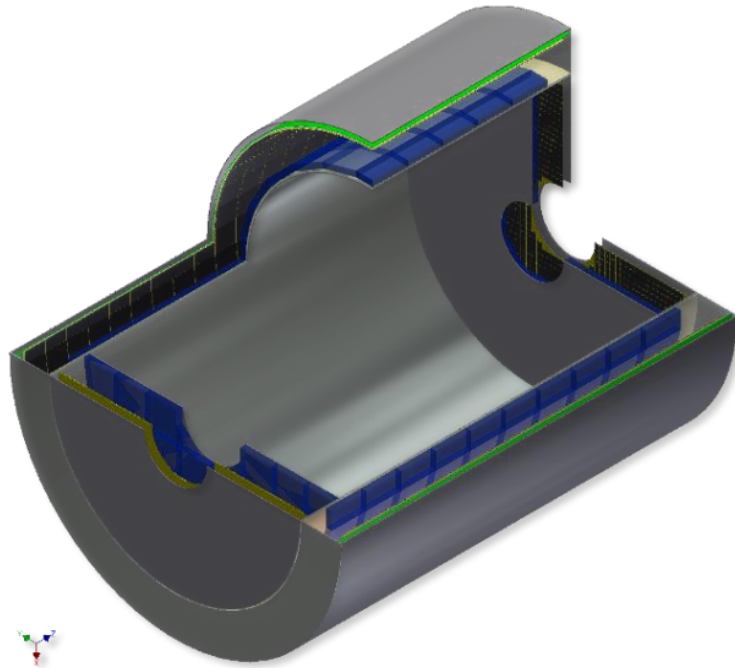


3-layer aerogel 115x115x41 mm³



T.Iijima et al., NIM A548 (2005) 383
A.Yu.Barnyakov et al., NIM A553 (2005) 70

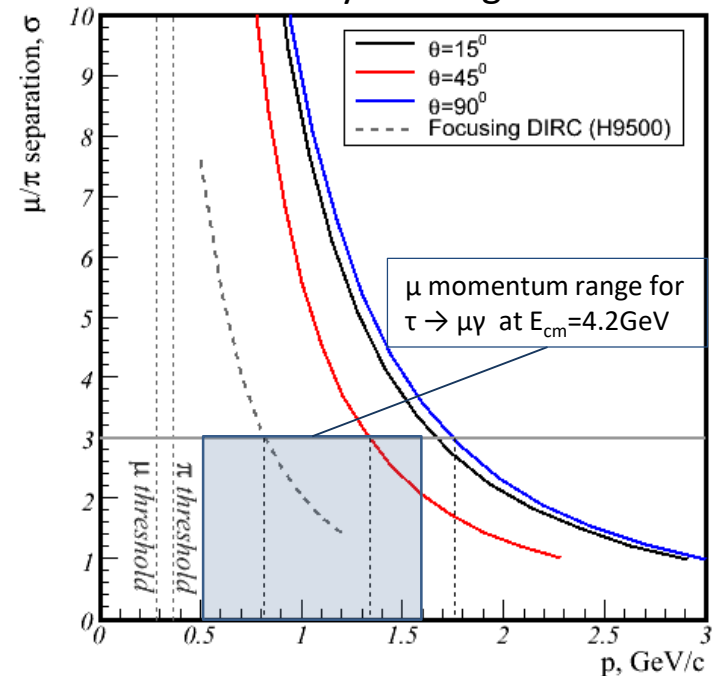
FARICH for Super Charm-Tau Factory



- Proximity focusing RICH
- **21 m²** photon detector area
- Use SiPMs due to 1T magnetic field
- $\sim 10^6$ pixels with 4 mm pitch
- 4-layer or gradient aerogel radiator

μ/π : MC simulation

MPPC S10362 3x3mm, D=200mm,
4-layer aerogel



μ/π is required for LFV search in $\tau \rightarrow \mu\gamma$.
Target sensitivity on $\text{Br}(\tau \rightarrow \mu\gamma) \sim 10^{-9}$

SiPMs in RICH application (single photons)

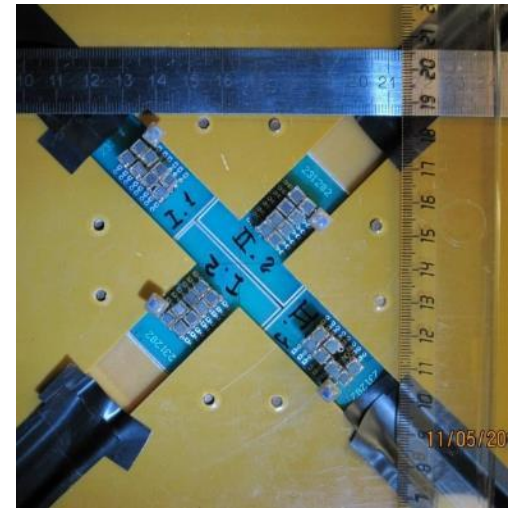
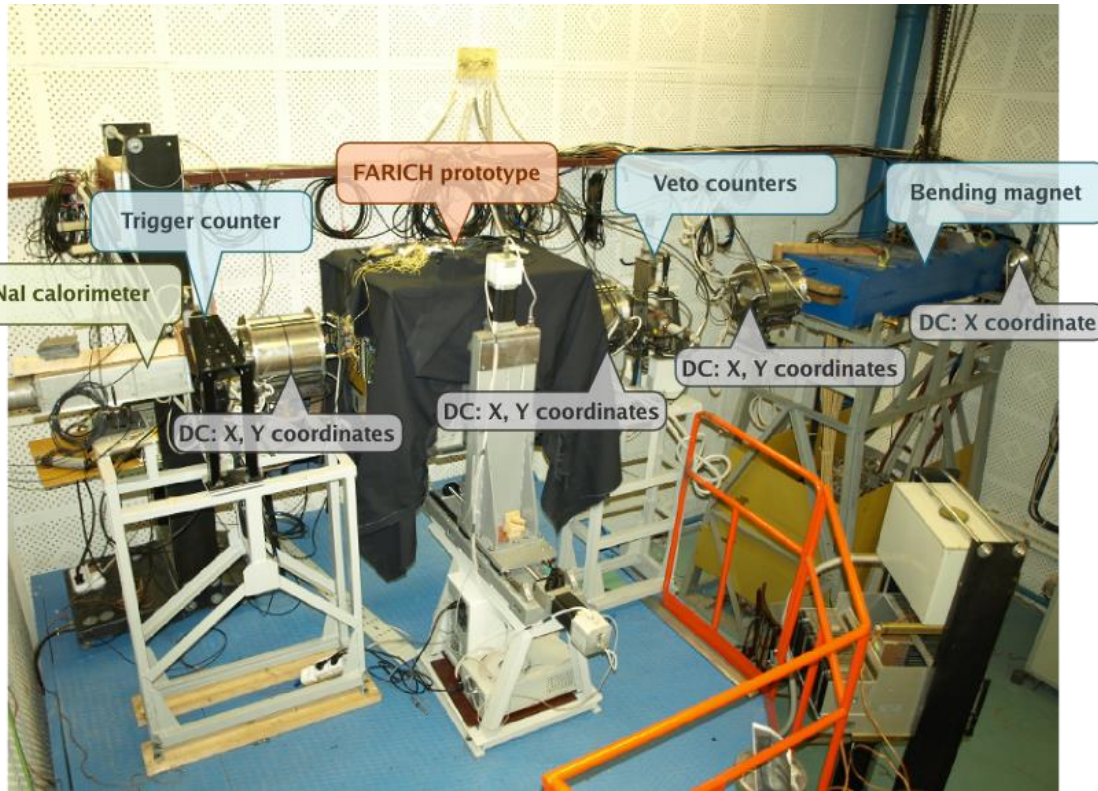
Pros

- High PDE
- Sub-ns timing resolution
- Immune to magnetic field
- Active/Total area ratio
- Very compact with low material budget

Cons

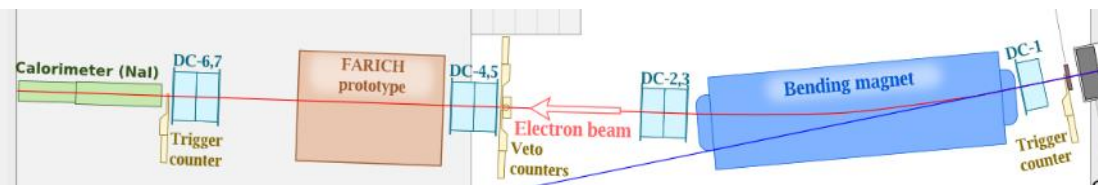
- High dark count rate (10-100 kHz/mm²)
- Radiation induced damage ($\sim 10^{10}$ n_{1MeV}/cm²)
 - S. Korpar et al., NIM A 594 (2008) 13
 - A.Y. Barnyakov et al., NIM A 732 (2013) 352
 - S. Korpar et al., NIM A 766 (2014) 107
 - M. Contalbrigo, NIM A 787 (2014) 224
 - I. Balossino et al., NIM A 876 (2017) 89

FARICH detector prototype with CPTA MRS APDs BINP e⁻ test beam in 2011

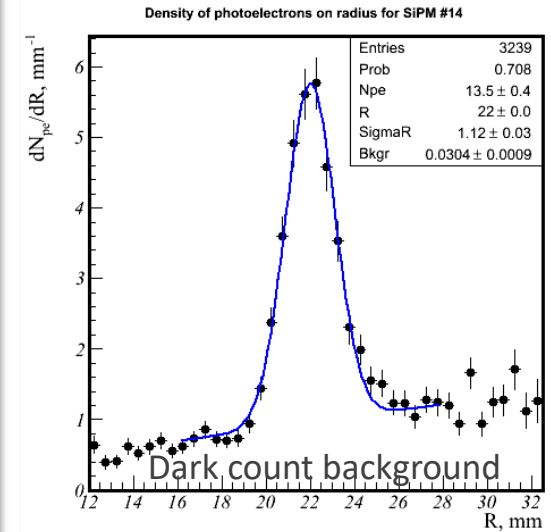
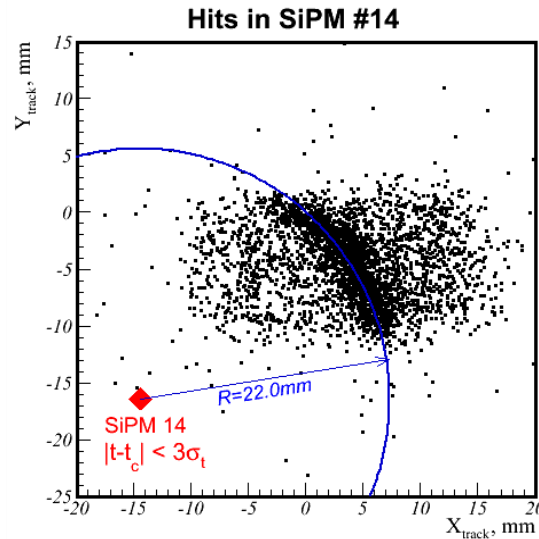
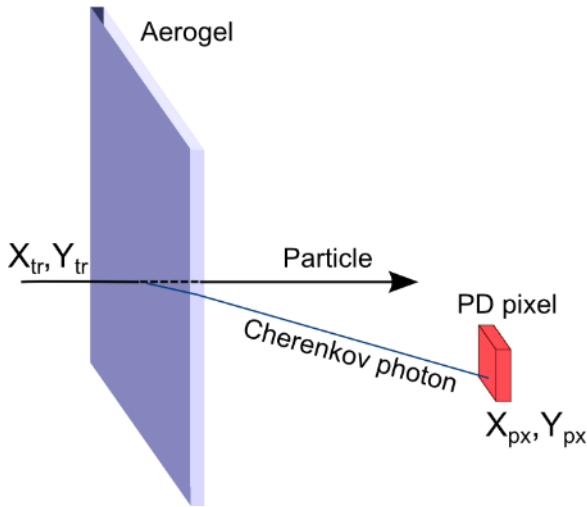


32 CPTA MRS APDs with active pixel size $2.1 \times 2.1 \text{ mm}^2$
DCR $\sim 5 \text{ MHz/device}$

4-layer aerogel focusing at 62 mm
 $n_1=1,050$ $t_1=6,2\text{mm}$
 $n_2=1,041$ $t_2=7,0\text{mm}$
 $n_3=1,035$ $t_3=7,7\text{mm}$
 $n_4=1,030$ $t_4=9,7\text{mm}$
 Size: $100 \times 100 \times 31 \text{ mm}^3$
 $L_{\text{sc}}(400\text{nm}) = 43\text{mm}$



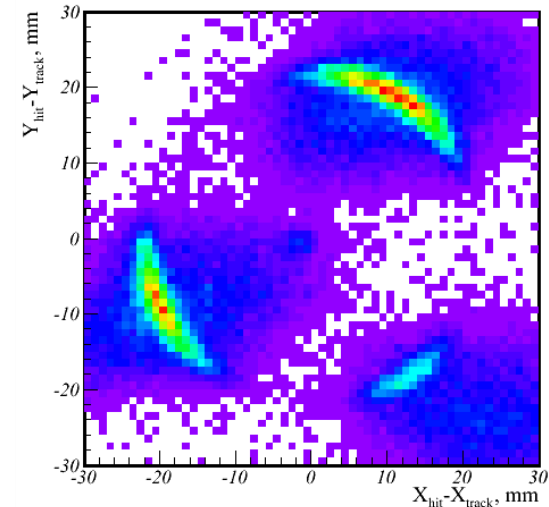
Cherenkov ring observation with single pixels



Given a **tracking system**, **wide beam** and enough **particle statistics**, a single PD pixel is enough to build the distribution of Cherenkov photons on R_{ch} (θ_{ch}).

Many pixels can be combined to improve accuracy and align the tracking system with the photon detector

Sum of all pixels w.r.t. track position



Analog SiPM vs Digital SiPM

Analog

- Established technology
- Great progress in improving parameters: PDE, DCR, RadHard
- High active/total area ratio
- Availability from different vendors
- Need for external analog-to-digital readout electronics – bulky detector, higher power consumption
- No control of individual SPADs

Digital

- On-chip integration of readout electronics – no need for ASICs
- Possibility to locate firing SPAD in low light applications – ~10 um resolution
- Better timing resolution
- Control of individual SPADs for inhibiting noisy ones
- Different designs for different applications – cost issue
- Limited possibilities for custom modifications due to CMOS production process

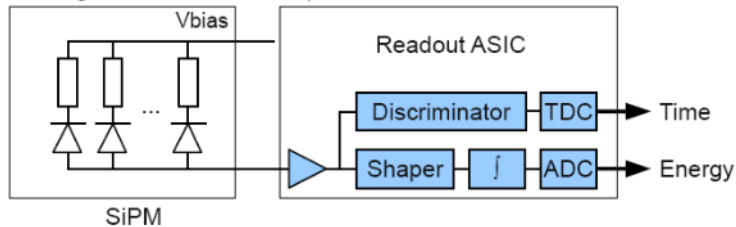


DPC is an Integrated, Scalable Solution

Analog SiPM

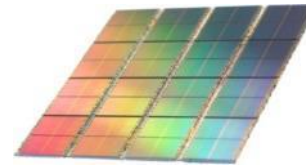


Analog Silicon Photomultiplier Detector

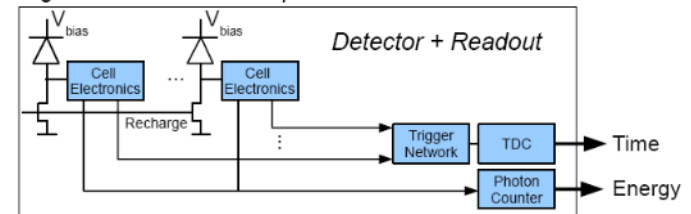


- discrete, limited integration
- analog signals to be digitized
- dedicated ASIC needed
- difficult to scale

Digital SiPM



Digital Silicon Photomultiplier Detector



- fully integrated thanks to CMOS
- fully digital signals
- no ASIC needed
- fully scalable

Courtesy of Philips Digital Photon Counting

DPC is an Integrated “Intelligent” Sensor by Philips Digital Photon Counting

DPC3200-22-44 – 3200 cells/pixel

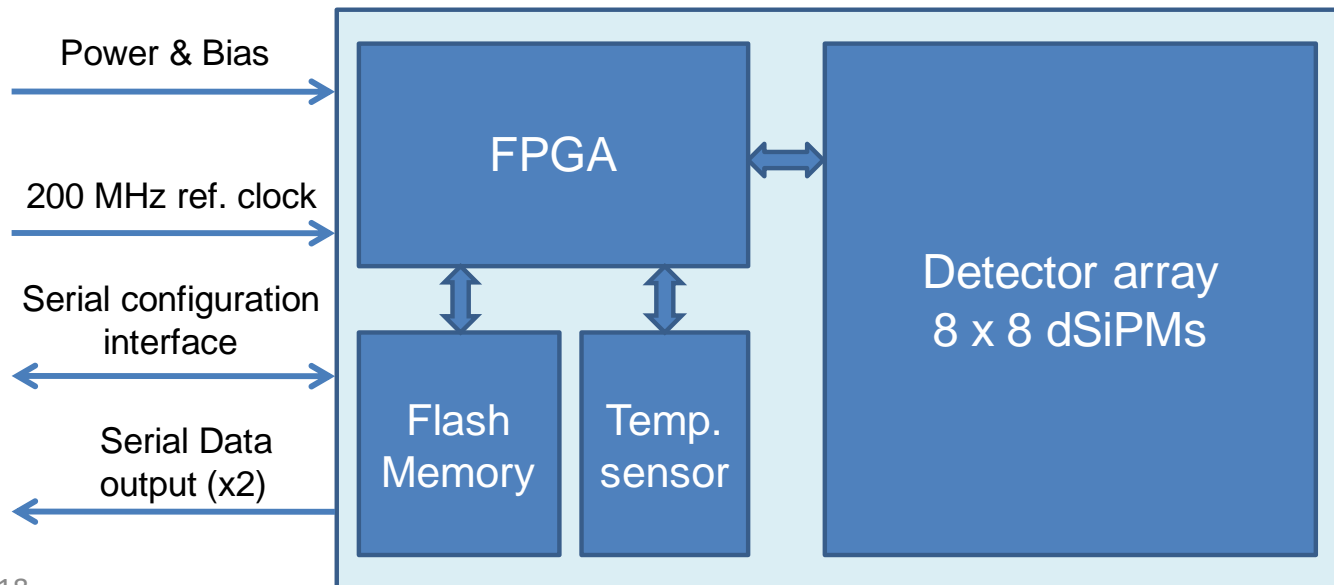
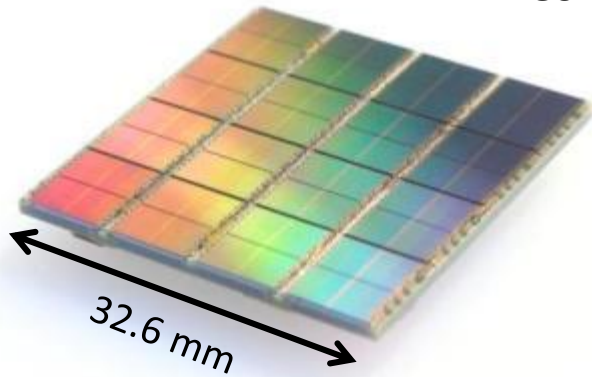
DPC6400-22-44 – 6396 cells/pixel

FPGA

- Clock distribution
- Data collection/concentration
- TDC linearization
- Saturation correction
- Skew correction

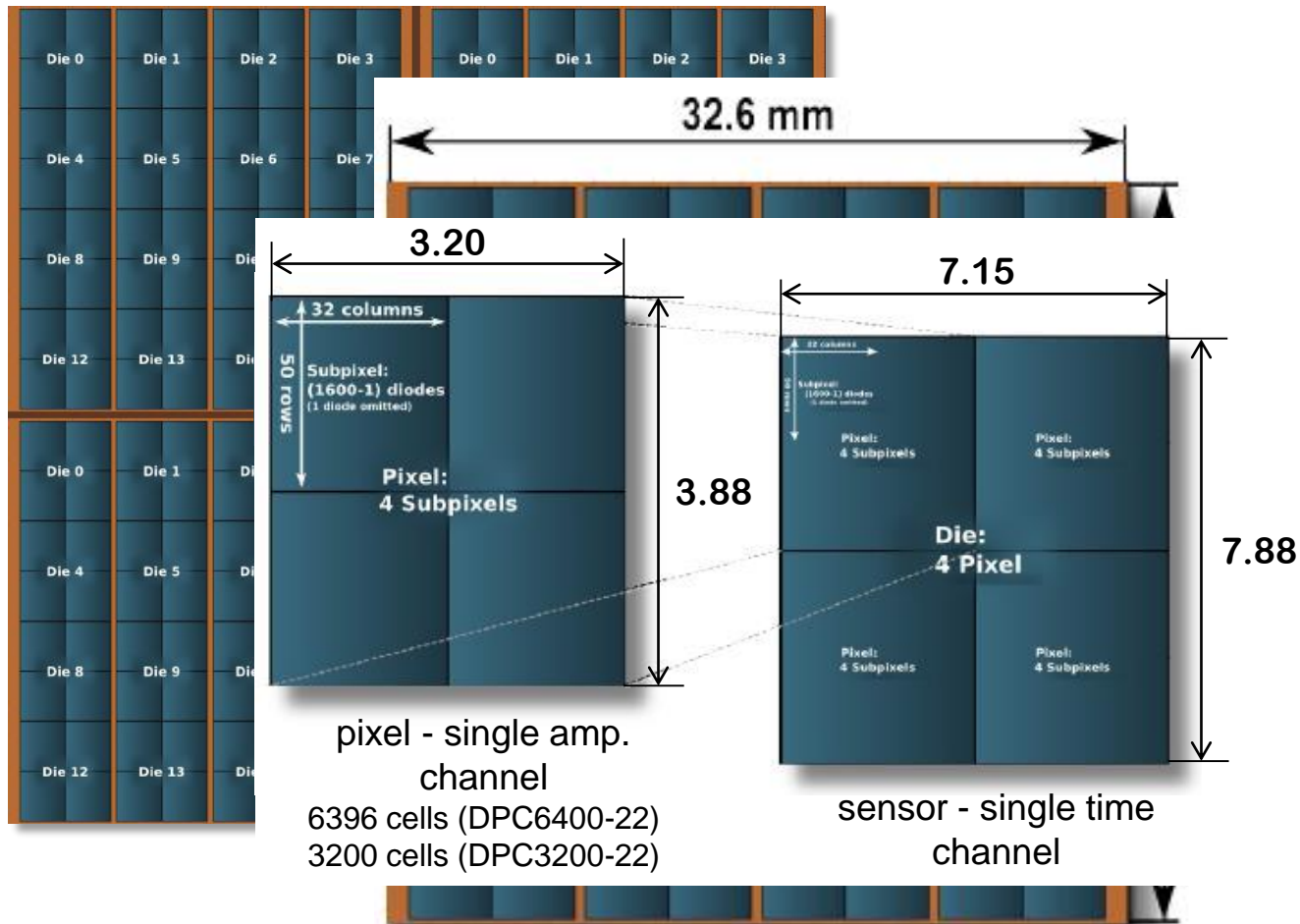
Flash

- FPGA firmware
- Configuration
- Inhibit memory maps



*Courtesy of
Philips Digital
Photon
Counting*

DPC readout units



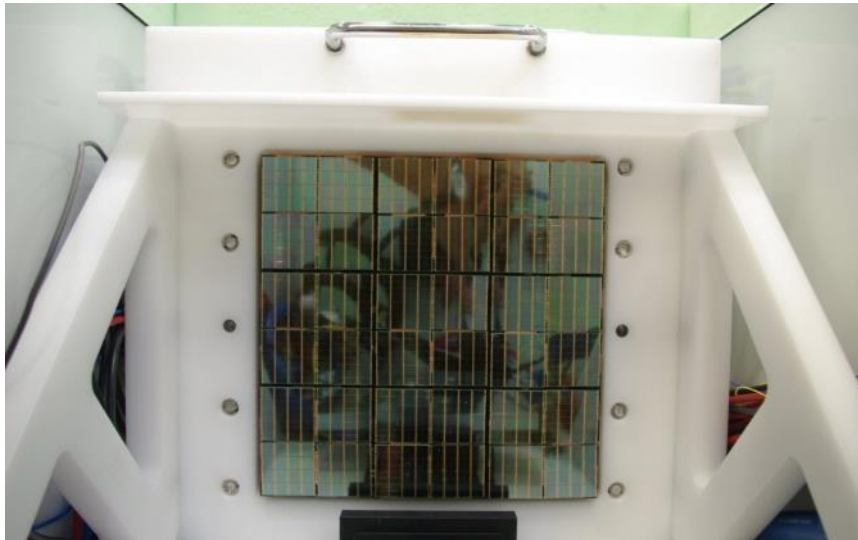
Geometrical efficiency $\approx 70\%$

FARICH prototype with DPC



4-layer aerogel

- $n_{\max} = 1.046$
- Thickness 37.5 mm
- Calculated focal distance 200 mm
- Hermetic container with plexiglass window to avoid moisture condensation on aerogel



Square matrix **20x20 cm²**

- Sensors: DPC3200-22-44
- 3x3 modules = 6x6 tiles = 24x24 dies = 48x48 pixels in total
- 576 timing channels
- **2304** amplitude channels (pixels **3.2x3.9 mm²**)
- 4 levels of FPGA readout: tiles, modules, bus boards, test board



PDPC-FARICH prototype beam test

CERN PS/T10, 2012

Main objective:

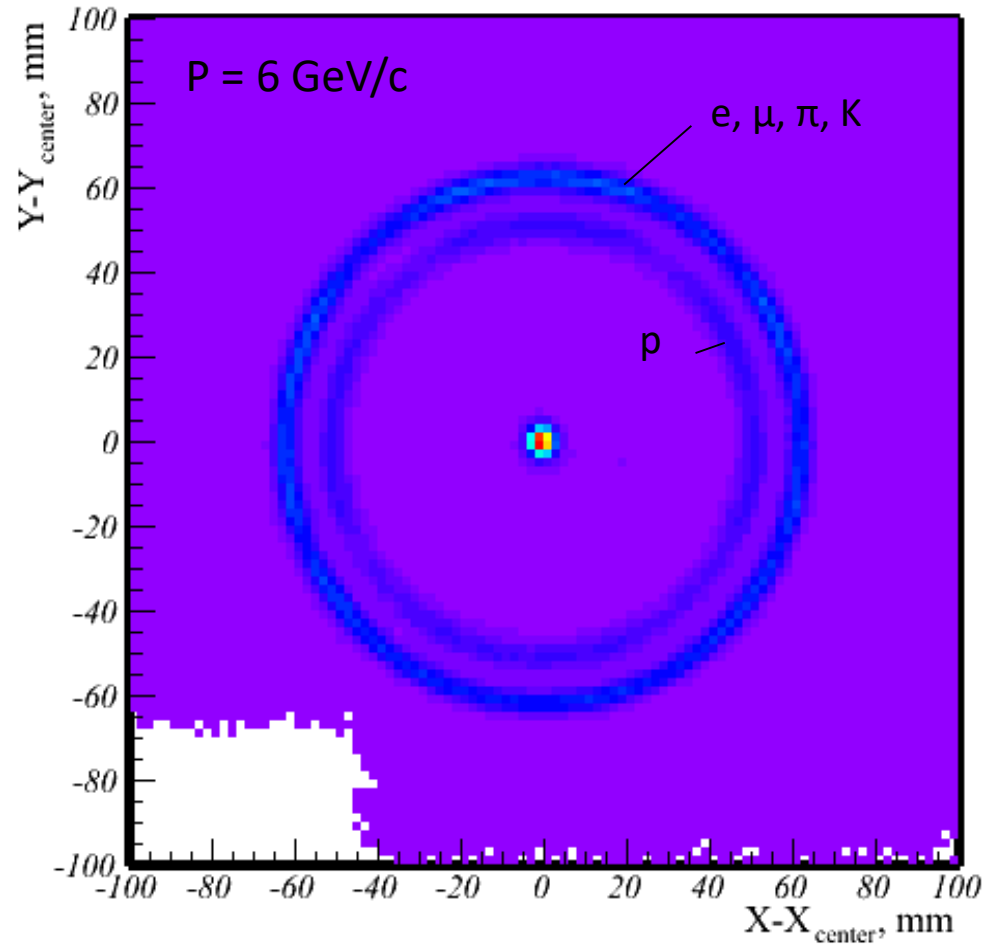
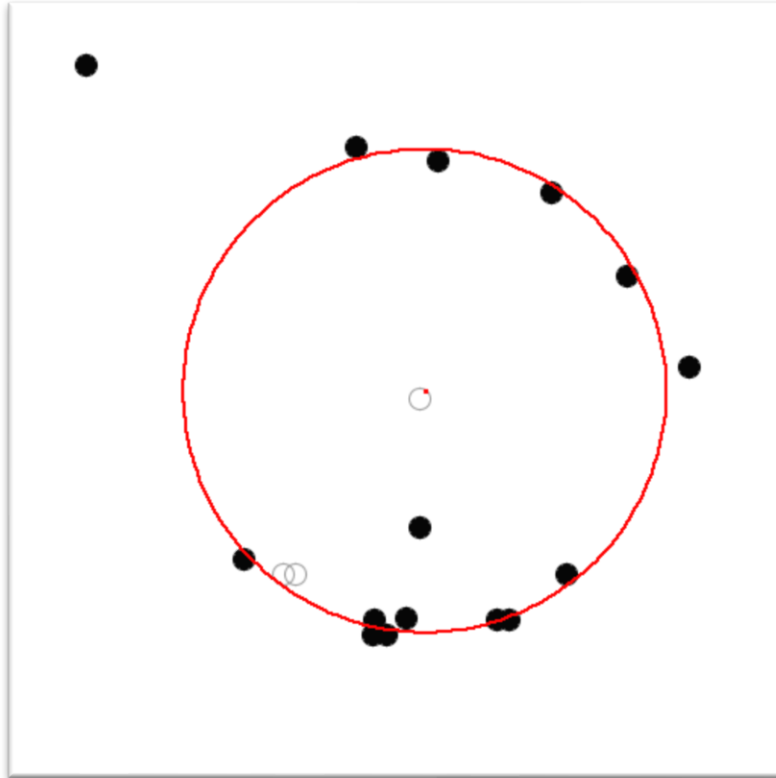
Proof of concept: full Cherenkov ring detection with a DPC array

Details:

- Operation temperature is -40°C to suppress dark count rate
 - Dead time is 720 ns.
 - $\text{DCR}(+25^{\circ}\text{C}) \approx 10 \text{ Mcps/sensor}$
single photon detection is not feasible!
 - $\text{DCR}(-40^{\circ}\text{C}) \approx 100 \text{ kcps/sensor}$
inefficiency is 7% .
- 2 stage cooling: LAUDA process thermostat + Peltiers.
- Dry N_2 constant flow to avoid condensation.

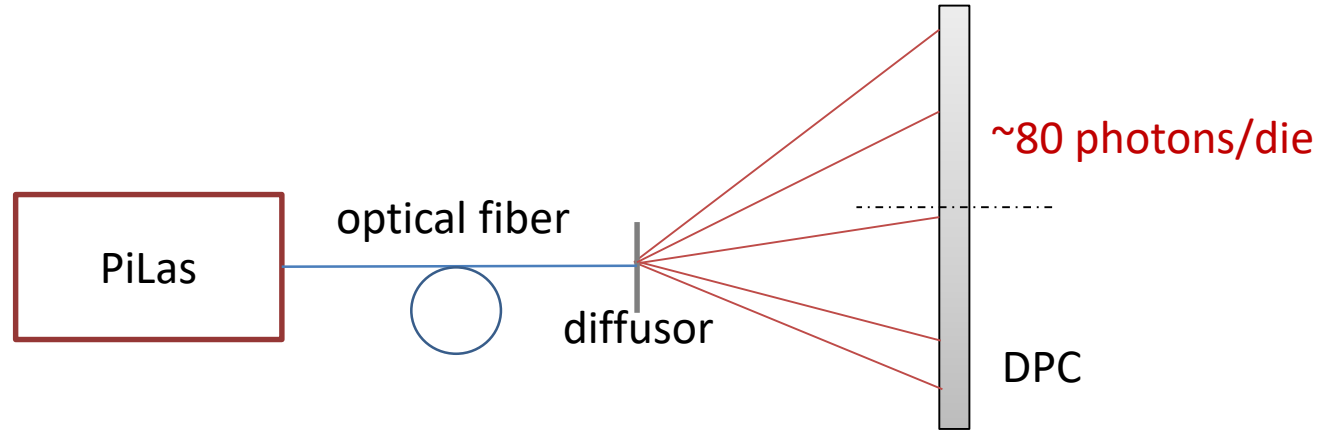


PDPC-FARICH: Cherenkov ring

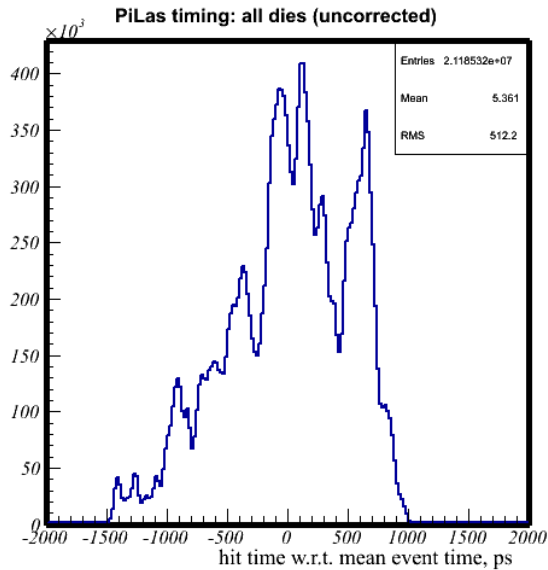


A.Yu. Barnyakov et al, NIM A 732 (2013) 352

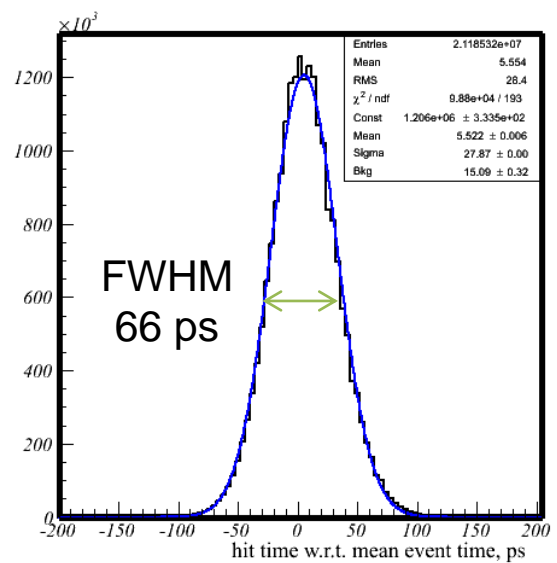
Clock skew correction between dies



Hit times w.r.t. mean hit time in event



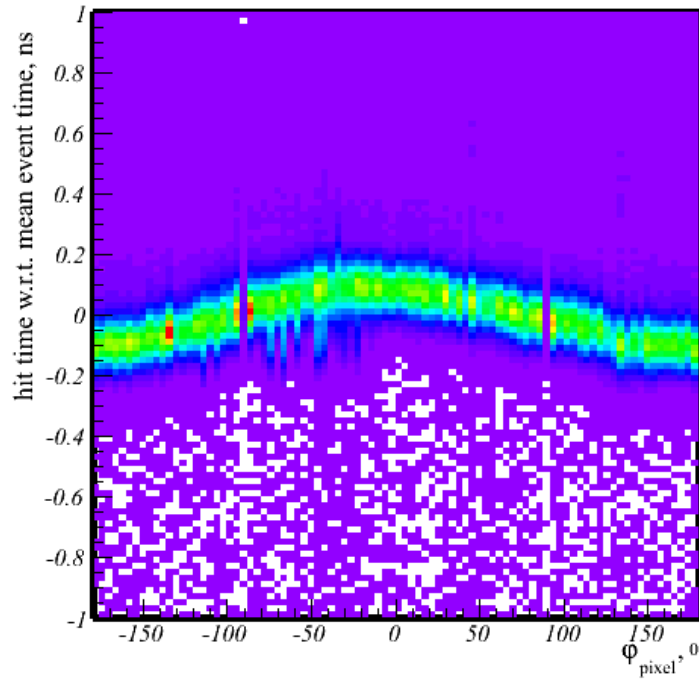
Clock skew correction between dies



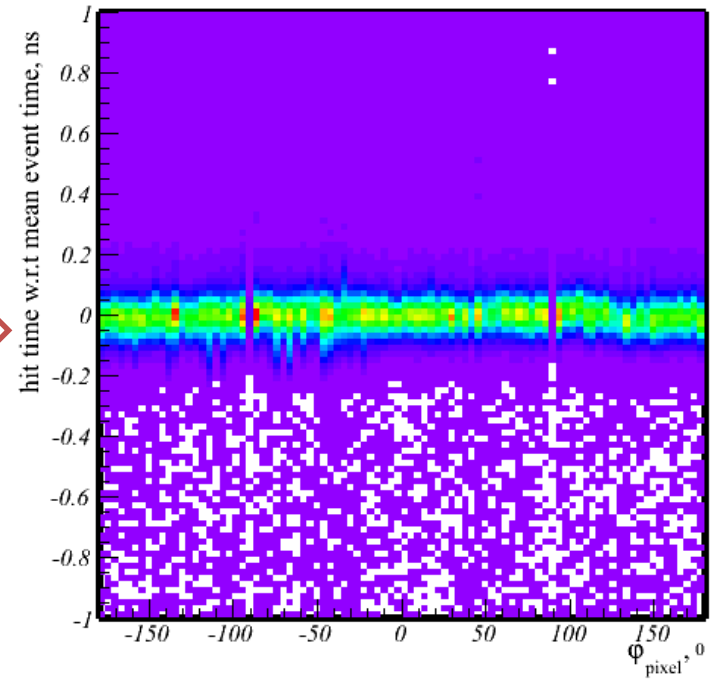
Timing correction by Cherenkov ring data

Hit timing vs φ -position

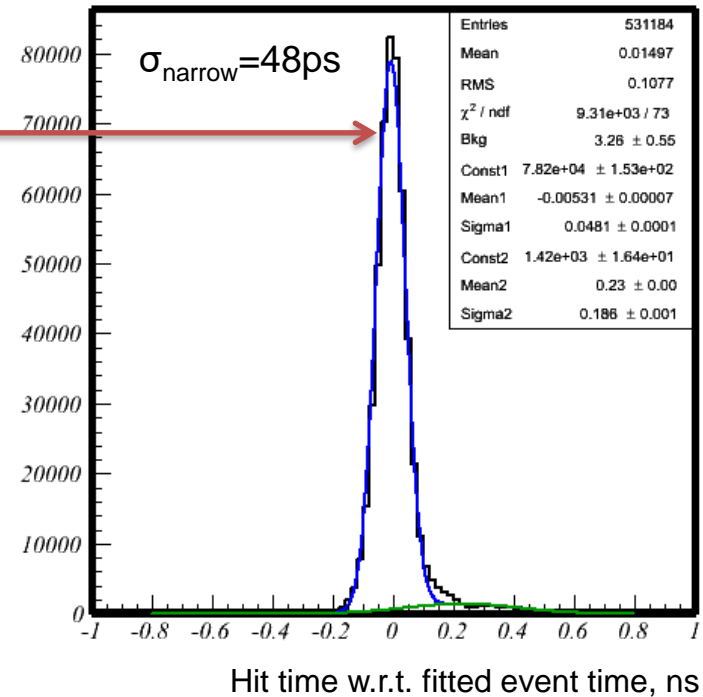
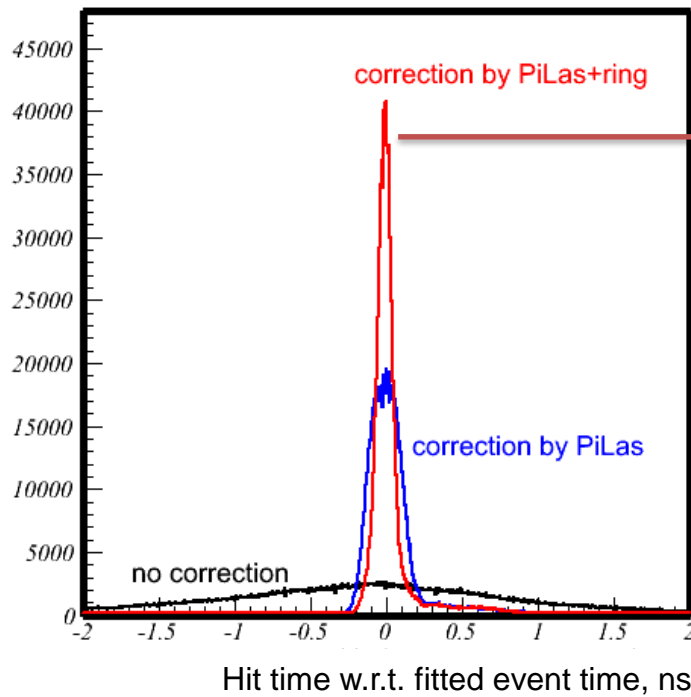
Before



After

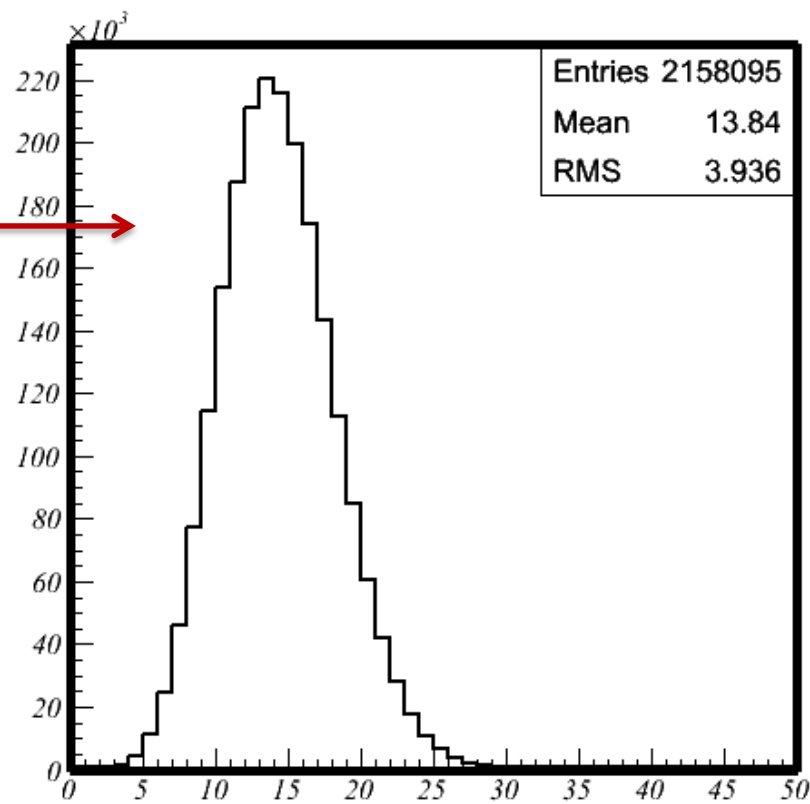
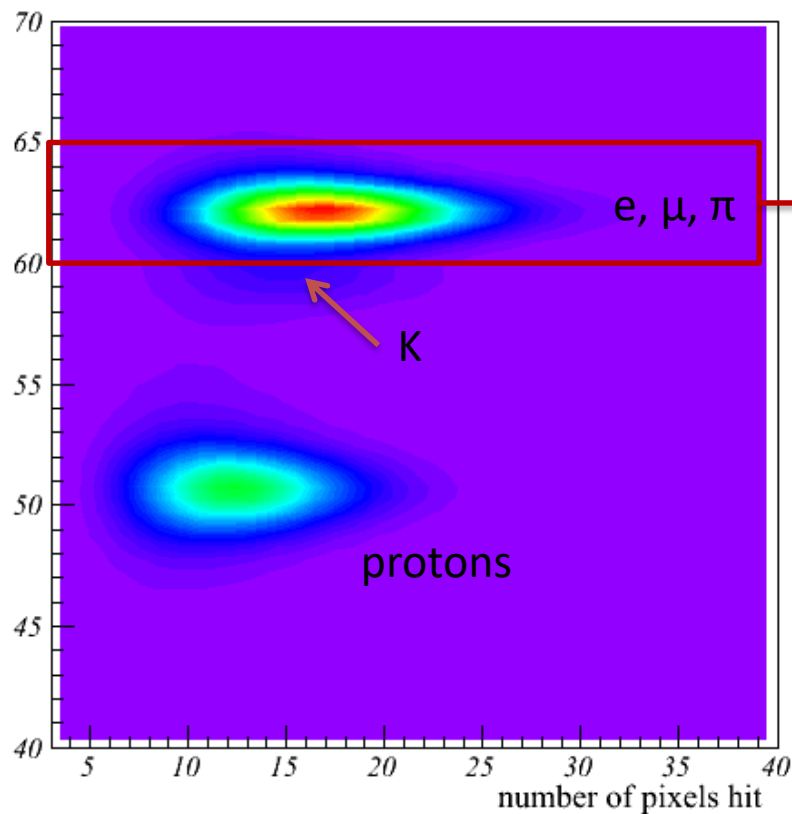


Single photon timing resolution for Cherenkov light



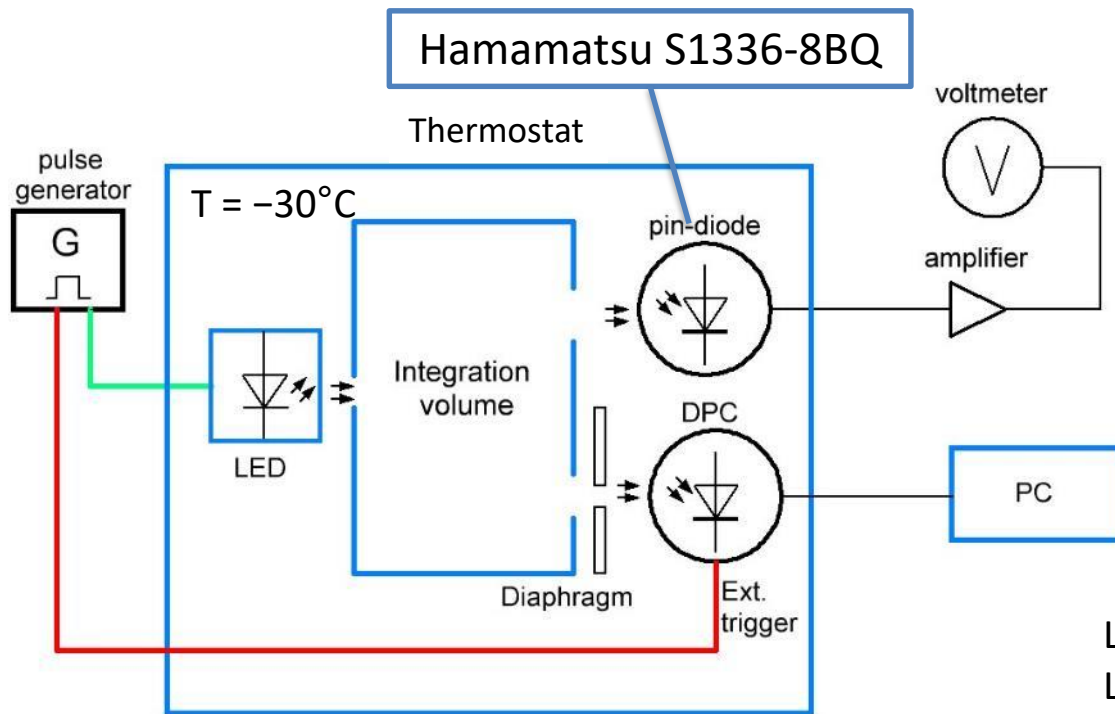
Fit two gaussians plus constant.
90% of area is contained in the narrow gaussian.

Number of photoelectrons

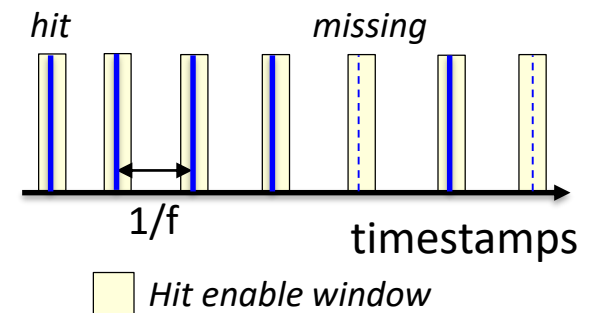


$N_{pe} = 12$ after taking into account crosstalks. $\sim 2x$ lower than expected.

Absolute PDE measurement of DPC



$$P(\text{hit}) = \frac{N_{\text{hit}}}{f \cdot T_{\text{run}}}$$



LED ON: $P(\text{hit}) = P(\text{signal} + \text{dc})$
 LED OFF: $P(\text{hit}) = P(\text{noise})$

$$P(0) = e^{-\mu}, \mu = \text{PDE} \cdot N_\gamma$$

Dark count rate and dead time taken into account:

$$P(0) = \frac{1 - P(\text{signal} + \text{dc}) / \text{LTR}}{1 - P(\text{dc}) / \text{LTR}}$$

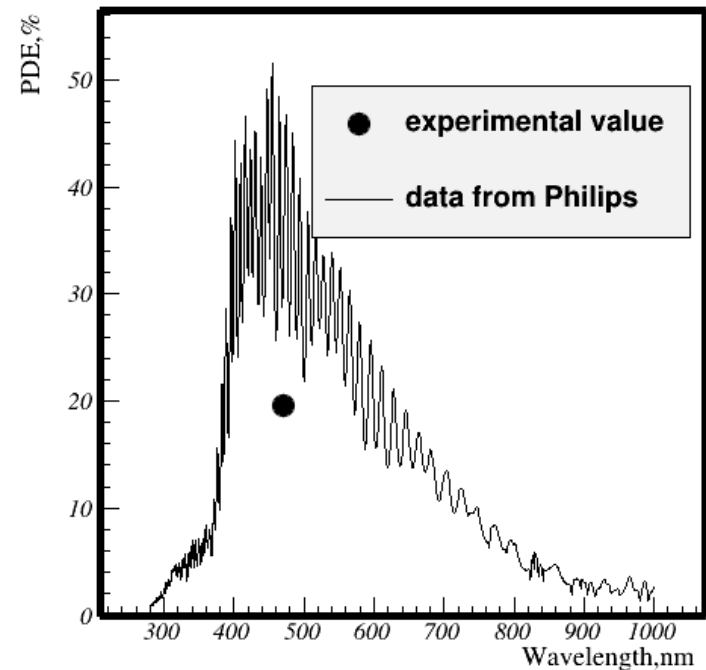
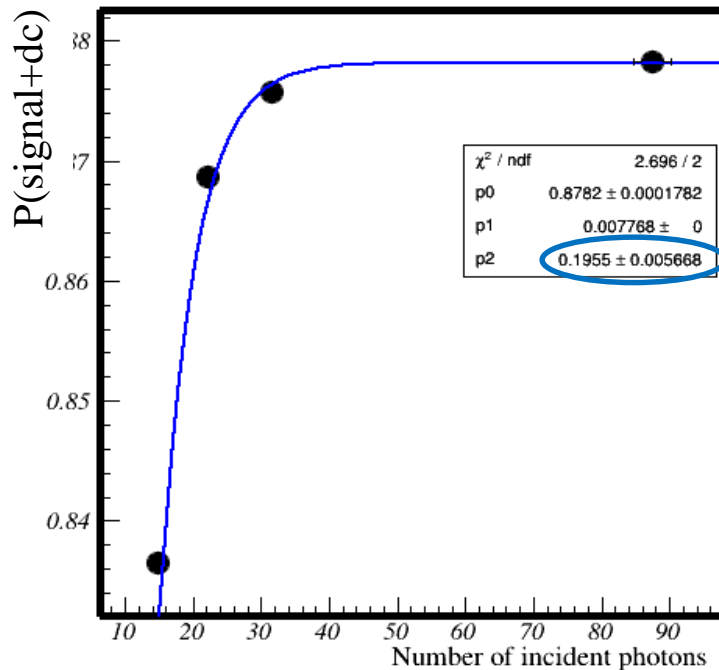
LTR – live time ratio, determined **only** by dark counts coming before LED pulse.

$$P(\text{signal} + \text{dc}) = \text{LTF} - (\text{LTF} - P(\text{dc})) e^{-\text{PDE} \cdot N_\gamma}$$

N_γ per pulse is determined from photocurrent of PIN diode and calibrated ratio of test/monitor channels

Absolute PDE of DPC

Fit $P(\text{signal}+\text{dc})$ as function of N_γ and extract PDE



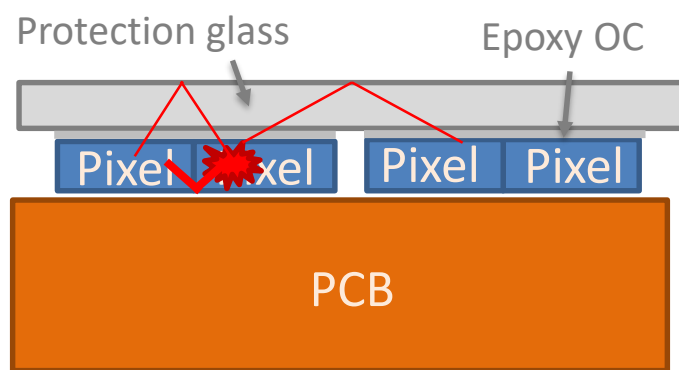
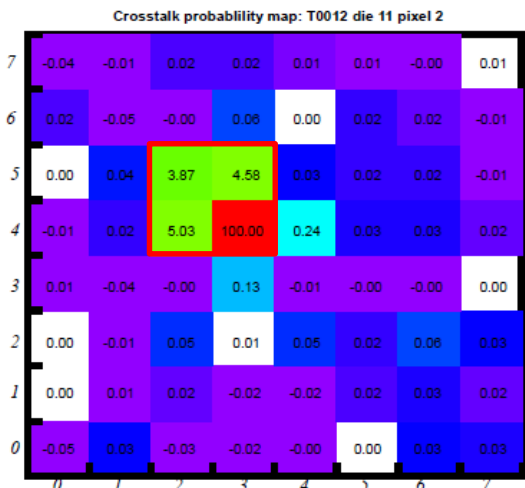
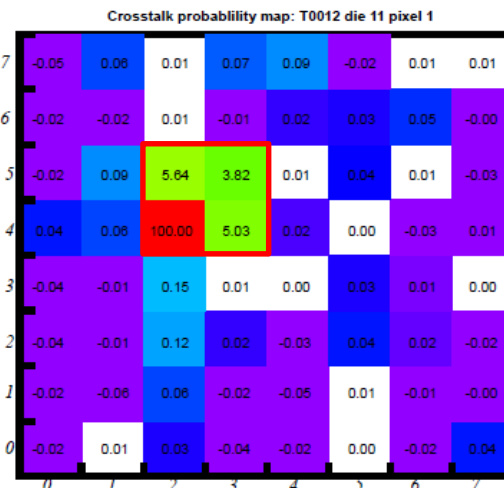
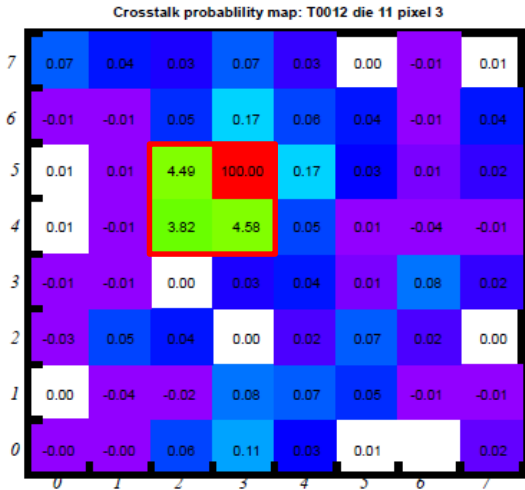
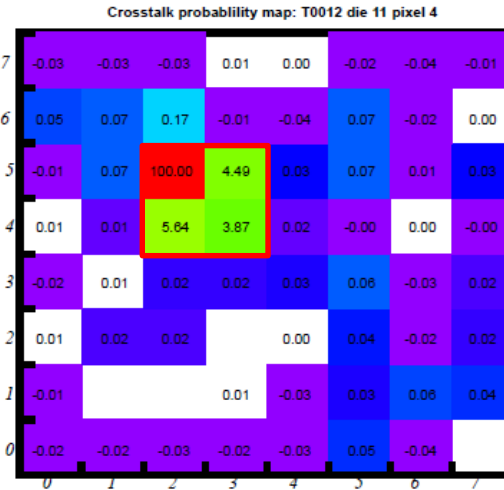
PDE(470 nm)
19±1% in our measurement vs 36% by PDPC measurement

Optical crosstalks in DPC

X-talks between pixels deteriorate position resolution

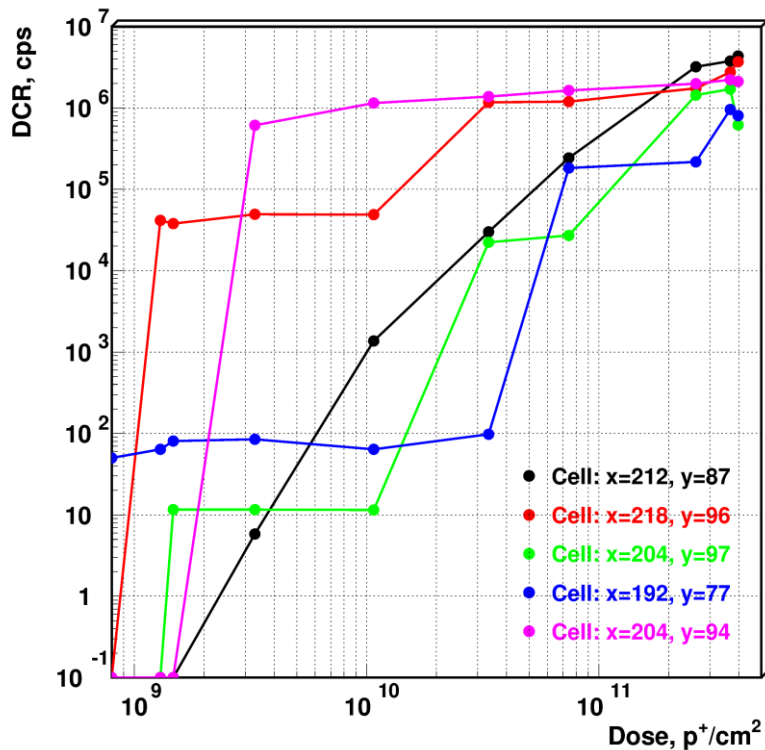
Crosstalk ways:

- between pixels of the same die (3-4%) go likely via Si substrate
- between neighboring dies (0.1-0.2%) go via protection glass

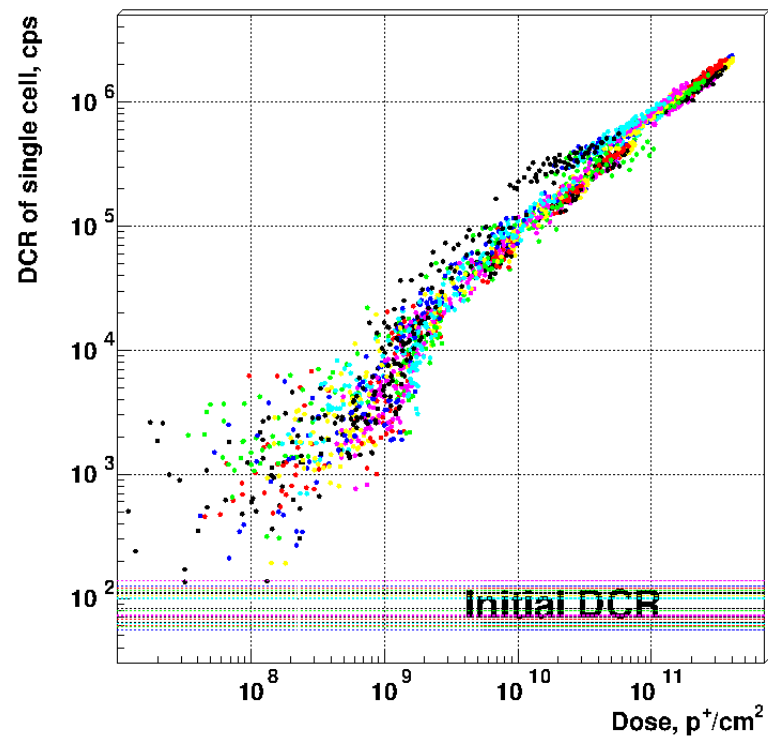


Irradiation of DPC tiles

proton beam (800 MeV/c) at COSY PS in FZ Jülich



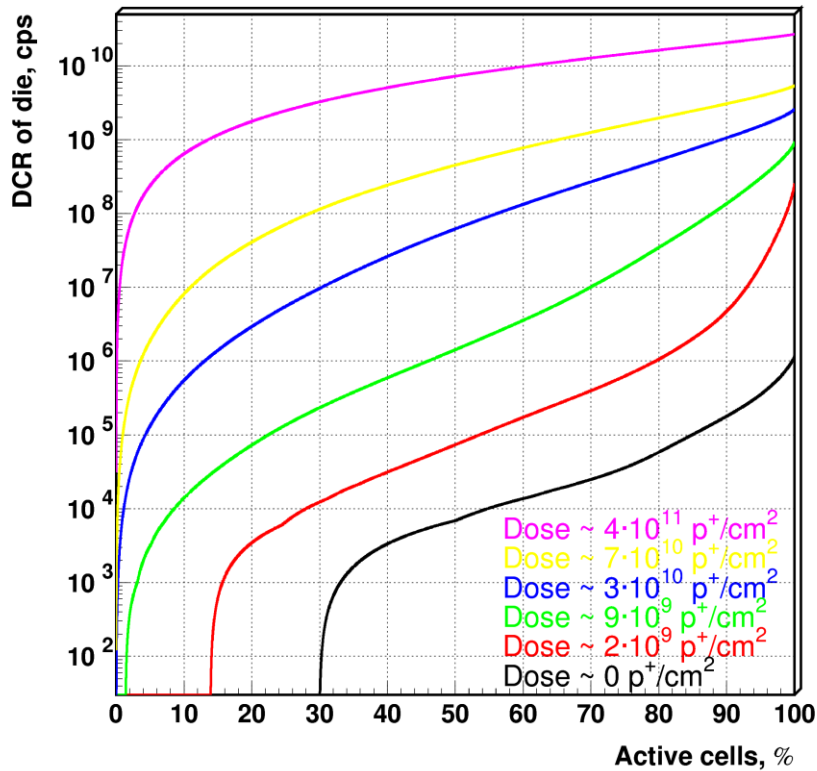
Die-averaged cell DCR vs fluence



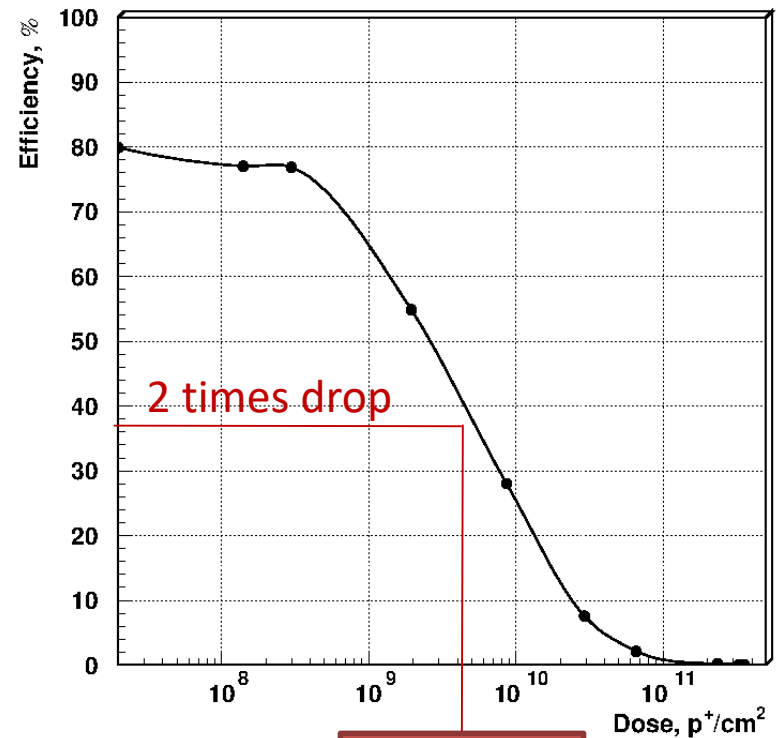
DPC tiles cooled to -18°C . Maximum fluence accumulated: $4 \cdot 10^{11}$ p/cm²

Radiation hardness study of DPC

Estimated die DCR vs active cell fraction



Estimated PDE degradation due to DCR increase with inhibiting most noisy cells



M.Yu. Barnyakov et al, NIM A 824 (2016) 83

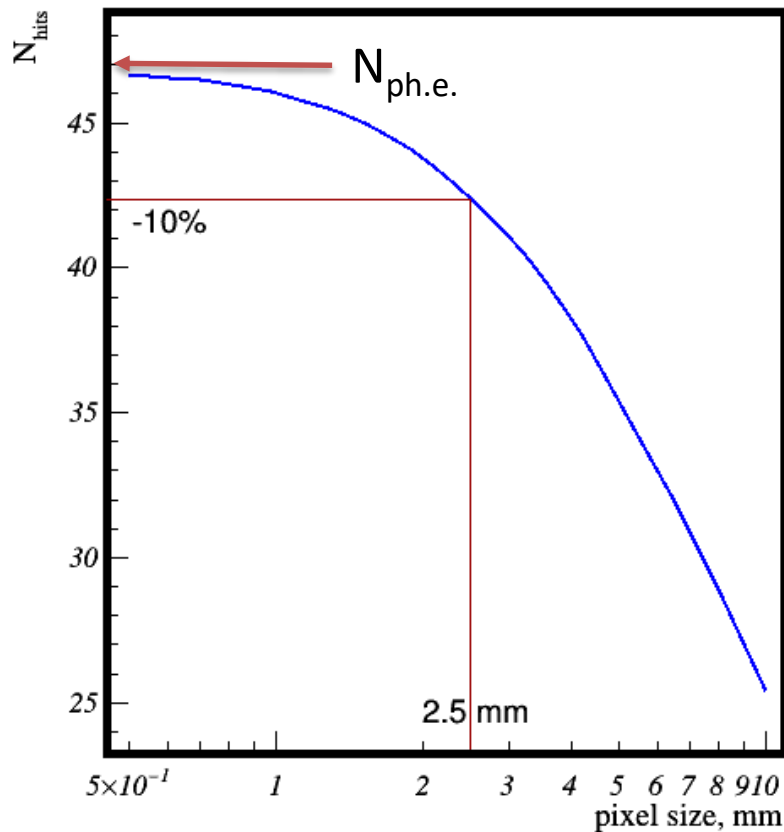
$4 \cdot 10^9$
 $n_{1\text{MeV}}/\text{cm}^2$

Desired characteristics of digital SiPMs for aerogel RICH

- PDE as high as possible: high active area ratio → amplitude dynamic range does not matter → large SPAD
- Room temperature operation → dark count rate at room temperature ≤ 10 kHz/mm²
- Dead time ratio $\leq 1\%$
- Position resolution $\sigma_x \leq 1$ mm: may be realized by determining position of a fired SPAD in an array of size $\sim 3 \times 3$ mm²
- SPTR ≤ 100 ps would be useful for DIRC-like detectors or suppressing uncorrelated background
- Radiation hard $\geq 10^{11}$ n_{1MeV}/cm², dead time ratio after irradiation ≤ 10 -20%, or cheap enough to be replaced after degradation
- Fast analog output for generating trigger from rings

Density of photoelectrons in aerogel RICH

Number of fired pixels vs pixel size



- PDE of MPPC S13361-3050
- Pixel packing factor - 80%
- Ring radius ~ 55 mm
- Ring width FWHM ~ 3 mm

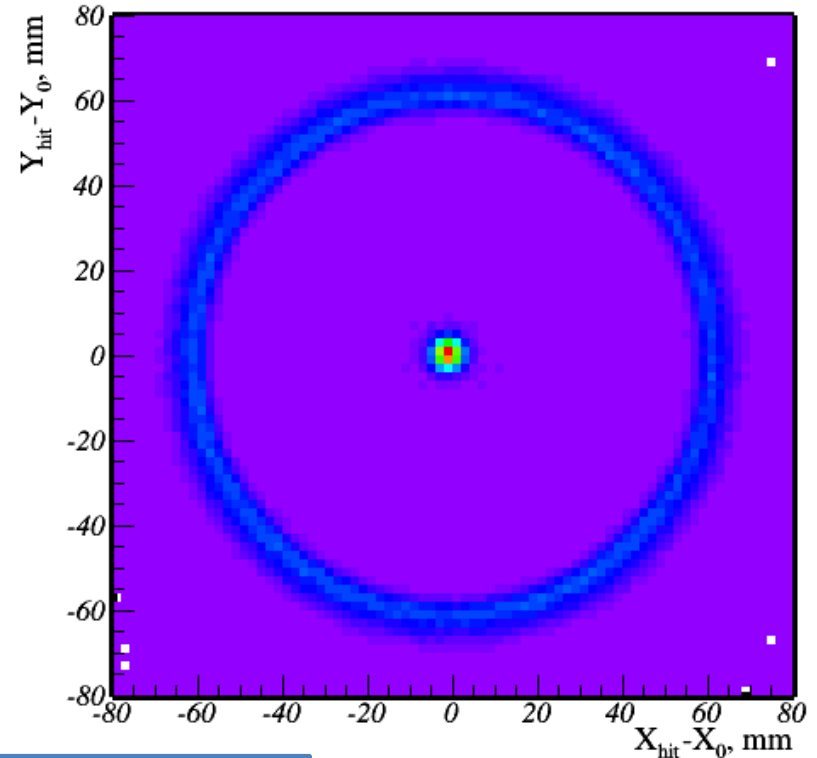
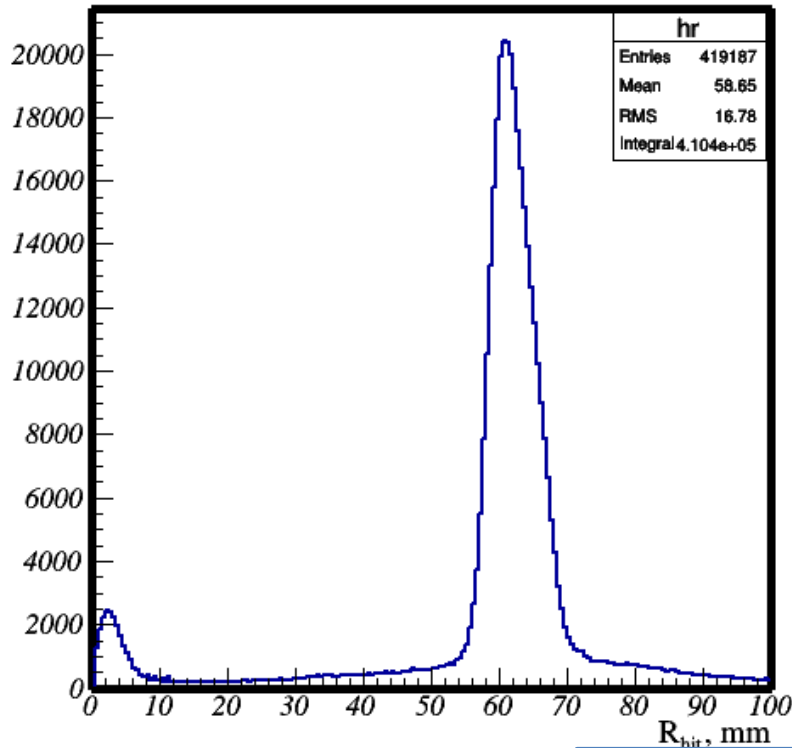
→ 10% loss of photons for pixel size 2.5 mm

Summary & conclusion

- Digital SiPMs are promising sensor candidates for RICH applications in visible & NUV range and only one in strong magnetic fields
- DPC parameters were studied: not quite suitable for aerogel RICH due to large dead time
- Looking for other dSiPM solutions for application in Super Char-Tau Factory (Novosibirsk)
- Welcome to collaboration!

Thank you for your attention!

Nice Cherenkov rings from aerogel detected by DPC at the e^- beam at BINP



2-layer aerogel of 40mm thick
D=160 mm